INTEGRATED CIRCUIT

TOSHIBA

TECHNICAL DATA

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT

TC74AC153P/F/FN

SILICON MONOLITHIC

DUAL 4 – CHANNEL MULTIPLEXER

The TC74AC153 is an advanced high speed CMOS DUAL 4 - CHANNEL MULTIPLEXER fabricated with silicon gate and double - layer metal wiring C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Each of these data (1C0 - 1C3, 2C0 - 2C3) is selected by the two address inputs A and B.

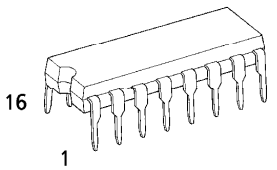
Separate strobe inputs ($1\overline{G}$, $2\overline{G}$) are provided for each of the two four - line sections.

The strobe input can be used to inhibit the data output ; the output is fixed in low level unconditionally.

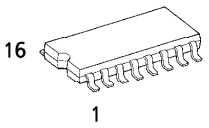
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES :

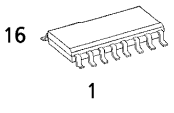
- High Speed ····· t_{pd} = 3.9ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ····· I_{CC} = 8μA(Max.) at Ta = 25°C
- High Noise Immunity ····· $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Symmetrical Output Impedance ··· $|I_{OH}| = I_{OL}$ = 24mA(Min.)
  Capability of driving 50Ω transmission lines.
- Balanced Propagation Delays ····· $t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range ···· V_{CC} (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74F153



P (DIP16 – P – 300A)
Weight : 1.00g (TYP.)

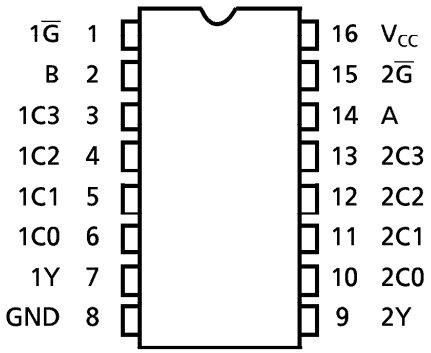


F (SOP16 – P – 300)
Weight : 0.18g (TYP.)



FN (SOL16 – P – 150)
Weight : 0.13g (TYP.)

PIN ASSIGNMENT



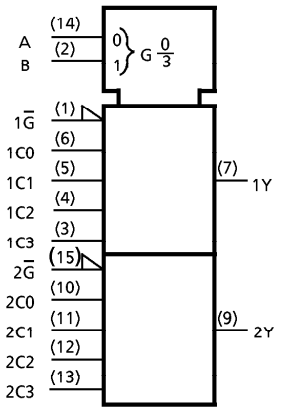
(TOP VIEW)

TRUTH TABLE

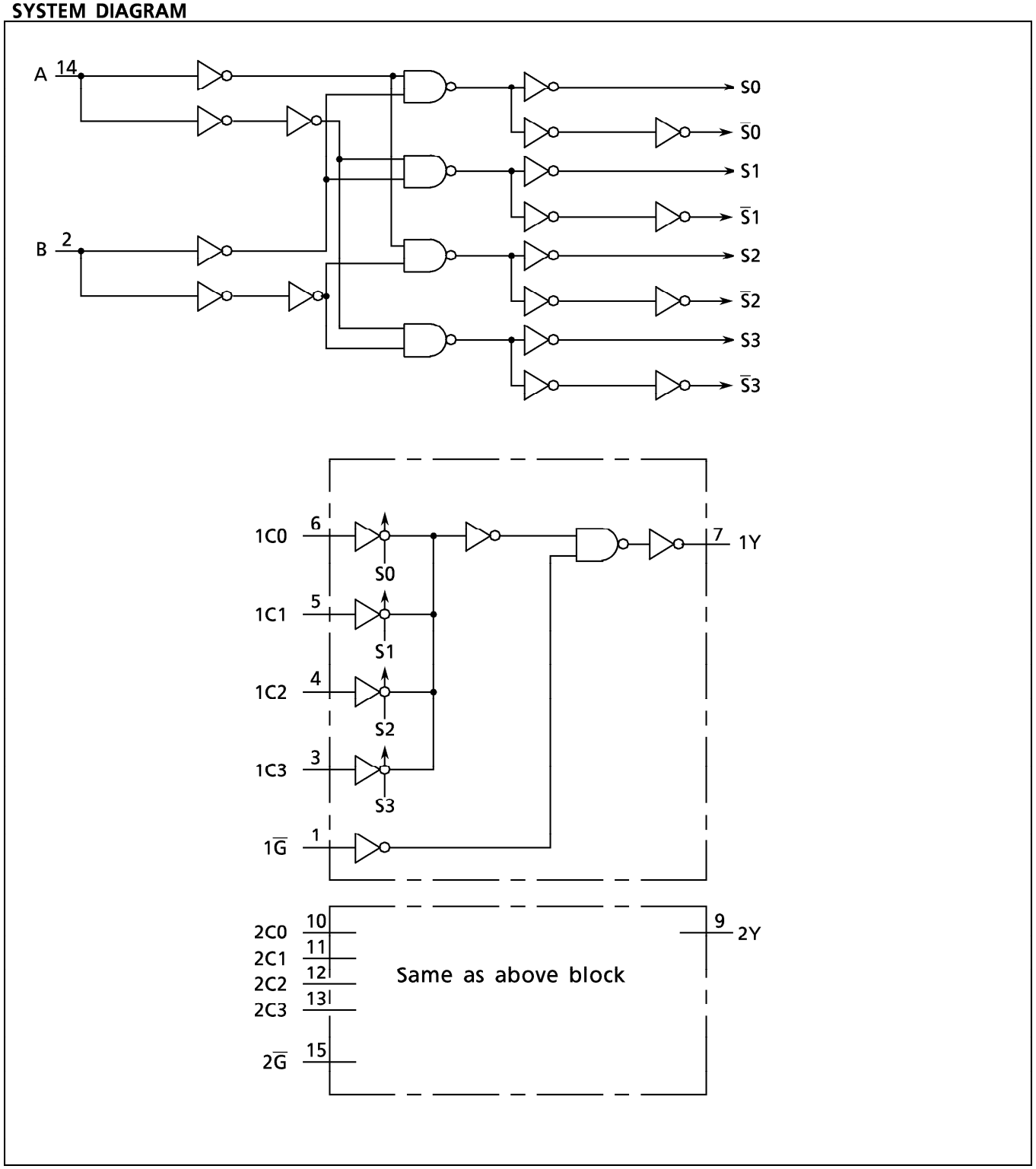
SELECT INPUTS		DATA INPUTS				STROBE	OUTPUT
B	A	C0	C1	C2	C3	$\overline{G}$	Y
X	X	X	X	X	X	H	L
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
L	H	X	L	X	X	L	L
L	H	X	H	X	X	L	H
H	L	X	X	L	X	L	L
H	L	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

X : Don't Care

IEC LOGIC SYMBOL



SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7.0	V
DC Input Voltage	V_{IN}	−0.5~V_{CC}+0.5	V
DC Output Voltage	V_{OUT}	−0.5~V_{CC}+0.5	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±50	mA
DC Output Current	I_{OUT}	±50	mA
DC V_{CC}/Ground Current	I_{CC}	±100	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T_{stg}	−65~150	°C

*500mW in the range of Ta = −40°C~65°C. From Ta = 65°C to 85°C a derating factor of −10mW/°C should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	V
Input Voltage	V_{IN}	0~V_{CC}	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	dt / dV	0~ 100 (Vcc = 3.3 ± 0.3V) 0~ 20 (Vcc = 5 ± 0.5V)	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V_{CC} (V)	Ta = 25°C MIN.	Ta = 25°C TYP.	Ta = 25°C MAX.	Ta = −40~85°C MIN.	Ta = −40~85°C MAX.	UNIT
High - Level Input Voltage	V_{IH}			2.0 3.0 5.5	1.50 2.10 3.85	— — —	— — —	1.50 2.10 3.85	— — —	V
Low - Level Input Voltage	V_{IL}			2.0 3.0 5.5	— — —	— — —	0.50 0.90 1.65	— — —	0.50 0.90 1.65	V
High - Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50μA	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	— — —	1.9 2.9 4.4	— — —	V
			I_{OH} = −4mA I_{OH} = −24mA I_{OH} = −75mA*	3.0 4.5 5.5	2.58 3.94 —	— — —	— — —	2.48 3.80 3.85	— — —	
Low - Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50μA	2.0 3.0 4.5	— — —	0.0 0.0 0.0	0.1 0.1 0.1	— — —	0.1 0.1 0.1	V
			I_{OL} = 12mA I_{OL} = 24mA I_{OL} = 75mA*	3.0 4.5 5.5	— — —	— — —	0.36 0.36 —	— — —	0.44 0.44 1.65	
Input Leakage Current	I_{IN}	V_{IN} = V_{CC} or GND		5.5	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	8.0	—	80.0	

* This spec indicates the capability of driving 50Ω transmission lines.
One output should be tested at a time for a 10ms maximum duration.

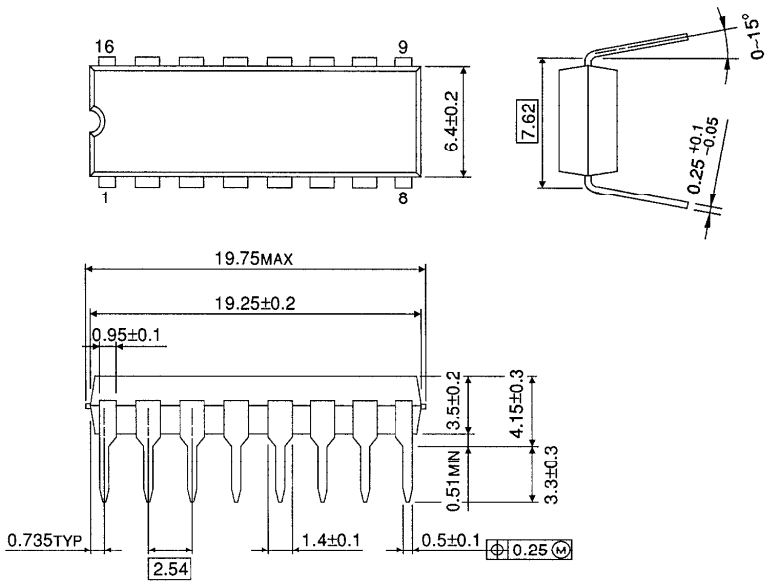
AC ELECTRICAL CHARACTERISTICS (C_L = 50pF , R_L = 500Ω , Input $t_r = t_f$ = 3ns)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = −40~85°C		UNIT
			V_{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (Cn−Y)	t_{pLH} t_{pHL}		3.3 ± 0.3 5.0 ± 0.5	— —	7.6 5.0	14.5 9.0	1.0 1.0	16.5 10.3	ns
Propagation Delay Time (A, B−Y)	t_{pLH} t_{pHL}		3.3 ± 0.3 5.0 ± 0.5	— —	10.5 6.6	20.5 10.5	1.0 1.0	23.4 12.0	
Propagation Delay Time ($\overline{G}$−Y)	t_{pLH} t_{pHL}		3.3 ± 0.3 5.0 ± 0.5	— —	6.8 4.4	13.3 8.0	1.0 1.0	15.2 9.1	
Input Capacitance	C_{IN}			—	5	10	—	10	pF
Power Dissipation Capacitance	C_{PD} (1)			—	54	—	—	—	

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

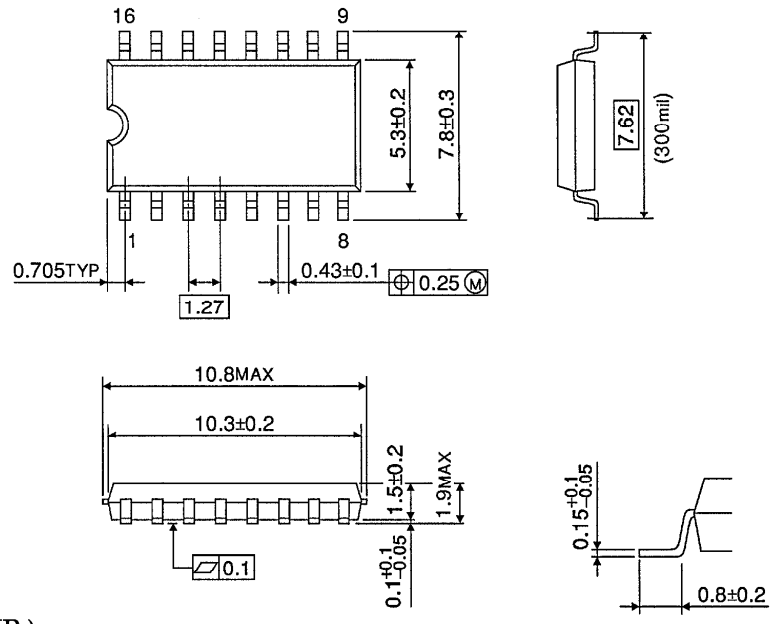
$$I_{CC}(opr.) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

DIP 16PIN OUTLINE DRAWING (DIP16−P−300A) Unit in mm



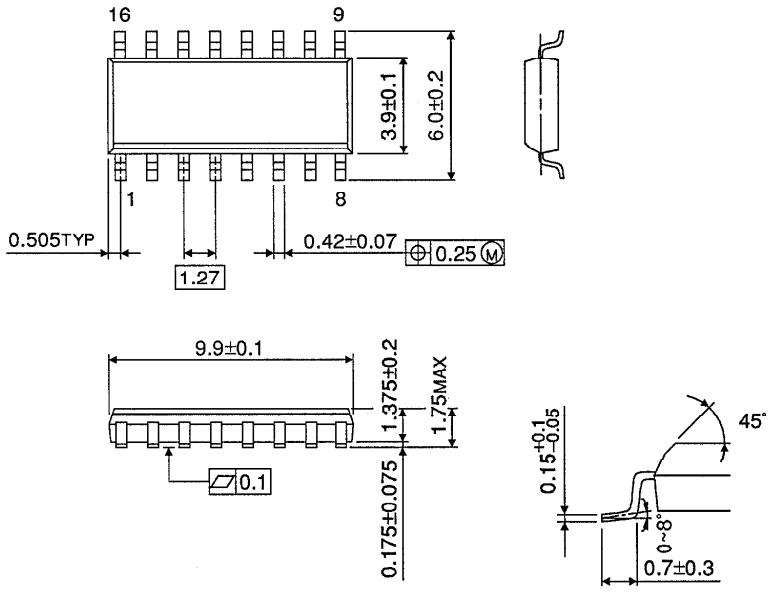
Weight : 1.00g (TYP.)

SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16−P−300) Unit in mm



Weight : 0.18g (TYP.)

SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16−P−150) Unit in mm



Weight : 0.13g (TYP.)